

iW765

Zero Standby Power AC/DC Secondary-Side Regulation Controller with Integrated Synchronous Rectification for USB PD 3.1 w/PPS

The iW765 is an AC/DC secondary-side controller for USB Power Delivery (PD) 3.1 with Programmable Power Supply (PPS) support which integrates a secondary-side regulation controller, interface protocol controller, USB V_{BUS} driver and synchronous rectifier controller into a single IC. The iW765 is designed for higher output power applications up to 100W+.

The iW765 allows rapid charge of USB PD PPS enabled mobile devices (MDs). It resides on the secondary side of an AC/DC travel adapter (TA) and allows the TA to be configured for multi-level output voltage and current.

The device also provides a peak power capability to allow for higher output current prior to entering constant-current mode.

The iW765 measures the output voltage and load current and sends the results to a digital compensator for closed-loop control of flyback converter. The digital control signal generated by the compensator is converted to an analog signal and transferred to primary controller via an optocoupler.

The iW765 controller is a hard-wired state machine, so no MCU coding is required. This eliminates potential malicious or inadvertent access to chargers or power supplies designed with the iW765 and prevents them from sourcing volt- ages via the USB cable higher than a smartphone, tablet, laptop or other product can handle, which may damage the product.

The iW765 is also an advanced synchronous rectifier (SR) controller with an integrated MOSFET driver. The device works with an external power MOSFET to replace the main rectifying diode on the secondary of a flyback converter. The SR control block with proprietary technologies optimizes the SR on/off timing and driving voltage to achieve best efficiency.

The iW765 should be paired with Renesas' high power-density Flyback primary-side controllers such as the iW9860 or iW9870 to achieve high efficiency, accurate voltage/current control and fast dynamic load response. Furthermore, iW9860/iW9870 and iW765 can enter an extremely low consumption state when MD is unplugged so that TA standby power is < 5mW (Zero standby power¹).

Features

- Zero standby power consumption with lowest system cost (< 5mW at 230V_{AC} when output USB cable is detached in a typical 45W USB PD travel adapter)¹
- Supports USB PD3.1 with PPS for output voltage from 3.3V to 21V in 20mV steps and output current in 50mA steps
- Proprietary peak power mode operation support
- High resolution accuracy multi-level output voltage and current control
- Built-in digital loop compensation to minimize the external component count
- Built-in synchronous rectification controller with integrated driver
- Optimized V_{DS}-based SR timing and driving control with wide output range
- Supports D- Impedance detection
- NFET driver for V_{BUS} switch
- Active fast discharge from a high voltage to 5V at MD unplug or from a high voltage level to a lower level upon request
- Hard-wired state machine
 - No MCU and firmware required
 - Prevents chargers and power supplies from being hacked and damaged
- Supports DCM and CCM operation
- 14-Lead TDFN package

Applications

 AC/DC adapters for USB PD enabled smart phones, tablets and other mobile devices

Contents

1.	Over	rview			
	1.1	Typical Application	3		
2.	Pin Information				
	2.1	Pin Assignments	4		
		Pin Description			
3.	Spec	cifications	5		
	3.1	Absolute Maximum Ratings	5		
	3.2	Thermal Specifications	5		
4.	Package Outline Drawings				
5.	Package Outline Drawings Ordering Information				
6.	Part Number Code Description				

1. Overview

1.1 Typical Application

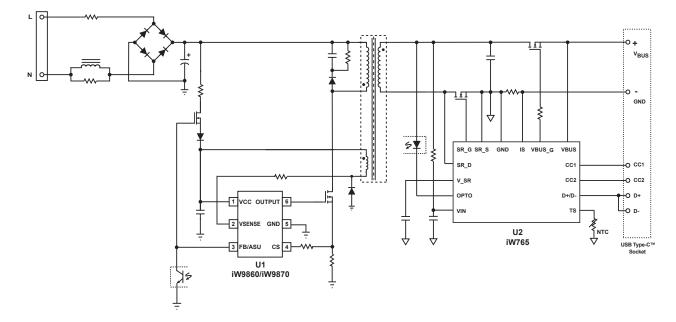


Figure 1. iW765 Typical Application Circuit for Multi-Level Voltage and Current (Using iW9860 as Primary-Side Controller, Achieving < 5mW No-Load Power Consumption).

2. Pin Information

2.1 Pin Assignments

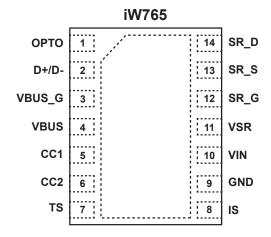


Figure 2. Top View

2.2 Pin Description

Pin Number	Pin Name	Туре	Description
1	ОРТО	Analog Output	Optocoupler driver to transfer the output regulation control signal to primary side.
2	D+/D-	Analog Input/Output	USB D+/D- signal, tied together.
3	VBUS_G	Analog Input/Output	Gate drive for external N-FET switch.
4	VBUS	Analog Input/Output	Connect to V _{BUS} after N-FET switch.
5	CC1	Analog Input/Output	Communication channel 1.
6	CC2	Analog Input/Output	Communication channel 2.
7	TS	Analog Input/Output	Temperature sensing pin. Connect to an external NTC resistor to measure the power adapter temperature.
8	IS	Analog Input	Output current sensing, connect to current sensing resistor "+" terminal.
9	GND	Ground	Ground, connect to current resistor "-" terminal.
10	VIN	Power Analog Input	Input of the internal LDO and output voltage sensing circuit.
11	V_SR	Power	Voltage supply for SR drive. Connect this pin to a capacitor.
12	SR_G	Analog Output	Synchronous rectifier MOSFET driver.
13	SR_S	Analog Input	Synchronous rectifier MOSFET source input.
14	SR_D	Analog Input	Synchronous rectifier MOSFET drain voltage sensing and the Pulse Linear Regulator (PLR) input.

3. Specifications

[The spec data in the following tables is for example purposes only and will vary per device or technology.]

3.1 Absolute Maximum Ratings

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions can adversely impact product reliability and result in failures not covered by warranty.

Parameter	Symbol	Minimum	Maximum	Unit
V_{VIN} DC supply voltage range (I _{VIN} = 12mA max)	V _{VIN}	-0.3	25	V
Continuous DC supply current at VIN pin (V _{VIN} = 12V)	I _{VO}		12	mA
SR_G peak output current	I _{SR_G}		±2	A
SR_G voltage	V _{SR_G}	-0.6	6	V
SR_D voltage (Note 1)	V _{SR_D}	-1.5	100	V
SR_D peak current	I _{DRAIN}	-40	300	mA
SR_S voltage	V _{SR_S}	-0.5	6	V
V_SR voltage	V_{V_SR}		6	V
OPTO voltage	V _{OPTO}	-0.6	25	V
D+/D- voltage	V _{D+/D-}	-0.3	25	V
CC1 voltage	V _{CC1}	-0.3	25	V
CC2 voltage	V _{CC2}	-0.3	25	V
IS voltage	V _{IS+}	-0.3	7	V
TS voltage	V _{SD}	-0.3	7	V
VBUS voltage (IBUS < 10mA)	V _{VBUS}	-0.7	25	V
VBUS_G voltage	V_{VBUS_G}	-0.7	30	V
Maximum Junction Temperature	T _{JMAX}	-40	150	°C
Maximum Storage Temperature Range	T _{STG}	-65	150	°C
ESD Rating	Value		Unit	
Human Body Model (Tested per JS-001-2017) (CC1/CC2	±8,000		V	
Human Body Model (Tested per JS-001-2017) (all other p	±2,000		V	
Latch-Up (Tested per JESD78E; Class 2, Level A)	±100		mA	

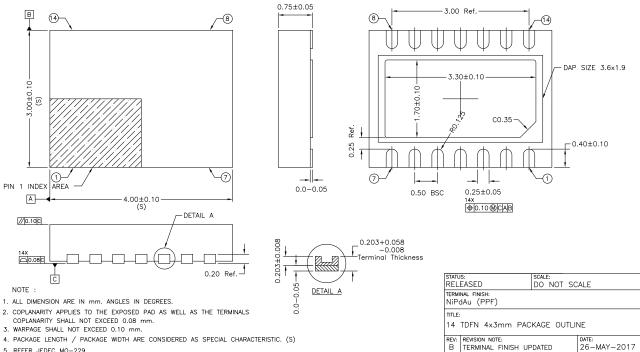
1. The DRAIN pin voltage should not be below -0.6V for more than 500ns.

3.2 Thermal Specifications

Thermal Resistance (Typical)	θ _{JA} (°C/W) [1]		
14-Led SOIC Package	TBD		

Package Outline Drawings 4.

The package outline drawings are located at the end of this document and are accessible from the Renesas website. The package information is the most current data available and is subject to change without revision of this document.



5. REFER JEDEC MO-229.

Figure 3. 14-Lead TDFN Package

Ordering Information 5.

	Options					
Part no.	Protocol and V/I Profile	Output Power	Peak Power Support	Primary-Side Controller	Package	Description
iW765-XX-YYYY	USB PD 3.1 PDO & APDO: support up to TBD	TBD	TBD	iW9860 iW9870	14-Lead TDFN	Tape & Reel ¹

Tape & Reel packing quantity is 3,000/reel. Minimum packing quantity is 3,000. 1.

Part Number Code Description 6.

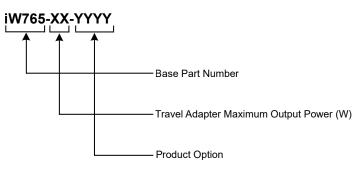


Figure 4. iW765 Part Number Decoder

IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers skilled in the art designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only for development of an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising out of your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

© 2023 Renesas Electronics Corporation. All rights reserved.

RoHS Compliance

Dialog Semiconductor's suppliers certify that its products are in compliance with the requirements of Directive 2011/65/EU of the European Parliament on the restriction of the use of certain hazardous substances in electrical and electronic equipment. RoHS certificates from our suppliers are available on request.

(Rev.1.0 Mar 2020)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu Koto-ku, Tokyo 135-0061, Japan www.renesas.com

Contact Information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit: www.renesas.com/contact/

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.